

HIGH SLEW RATE OP AMP**SE/NE538****DESCRIPTION**

The SE/NE538 is a new generation operational amplifier featuring high slew rates combined with improved input characteristics. Internally compensated for gains of 5 or larger, the SE538 offers guaranteed minimum slew rates of 40V/ μ s or larger. Featuring 2mV max input offset voltage, the 538 is a single amplifier. Industry standard pin out and internal compensation allow the user to upgrade system performance by directly replacing general purpose amplifiers, such as 748, 101A and 741.

FEATURES

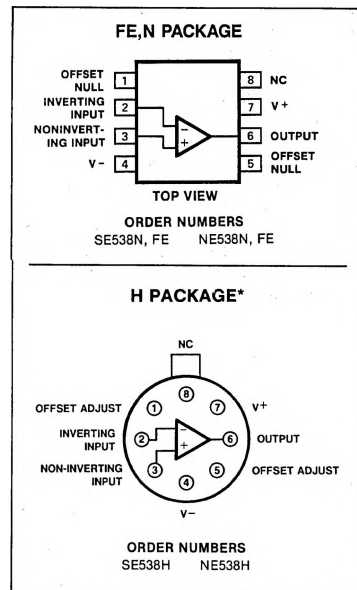
- 2mV input offset voltage
- 80nA max input offset current
- Short circuit protected
- Offset null capability
- Large common mode and differential voltage ranges
- 60V/ μ s slew rate (gain of +5, -4 min)
- 6MHz gain bandwidth product (gain +5, -4 minimum)
- Internal frequency compensation (gain of +5, -4 minimum)
- Pin out: 538 same as 741 (single)

ABSOLUTE MAXIMUM RATINGS^{1,2,3}

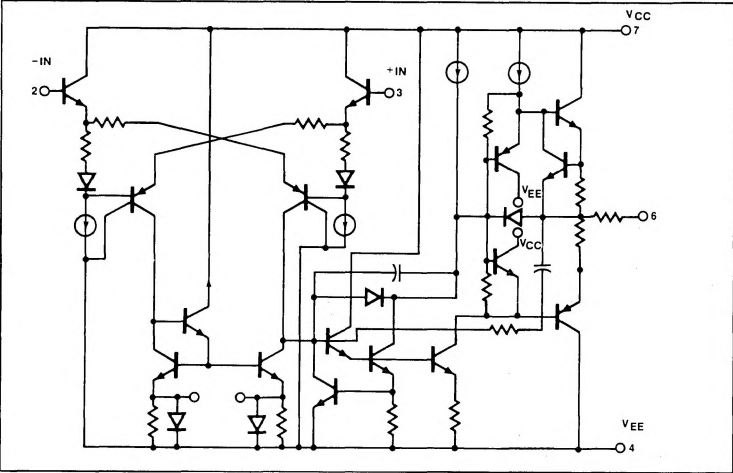
PARAMETER	RATING	UNIT
V _{CC} Supply voltage		
SE military grade	± 22	V
NE commercial grade	± 18	V
P _D Internal power dissipation	1000	mW
FE package		
P _D Internal power dissipation ¹	500	mW
N package		
P _D Internal power dissipation ¹	800	mW
H package		
Differential input voltage	± 30	V
Input voltage ²	± 15	V
Operating temperature range		
SE military grade	-55 to +125	°C
NE commercial grade	0 to 70	°C
Output short circuit ³	indefinite	
Storage temperature range	-65 to +150	°C
Lead temperature (solder, 60sec.)	300	°C

NOTES

1. Rating applies for thermal resistances of 240°C/W and 150°C/W junction to ambient for N and H packages. Maximum chip temperature is 150°C.
2. For supply voltages less than ± 15 V, the absolute maximum input voltage is equal to the supply voltage.
3. Short circuit may be to ground or either supply. Rating applies to 125°C case temperature or 75°C ambient temperature.



EQUIVALENT SCHEMATIC (EACH AMPLIFIER)



DC ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$ unless otherwise specified.

PARAMETER	TEST CONDITIONS	SE538			NE538			UNIT
		Min	Typ	Max	Min	Typ	Max	
V_{OS} Input offset voltage	$R_S \leq 10\text{k}\Omega$ $R_S \leq 10\text{k}\Omega$, over temp.		0.7	4.0 5.0		2.0	6.0 7.0	mV mV
ΔV_{OS} Input offset voltage drift	$R_S = 0\Omega$, over temp.		4.0			6.0		$\mu\text{V}/^\circ\text{C}$
I_{OS} Input offset current	Over temp.		5	20 40		15	40 80	nA nA
ΔI_{OS} Input offset current	Over temp.		25			40		$\text{pA}/^\circ\text{C}$
I_B Input current	Over temp.		45	80 200		65	150 200	nA nA
ΔI_B Input current	Over temp.		50			80		$\text{pA}/^\circ\text{C}$
V_{CM} Input common mode voltage range		± 12	± 13		± 12	± 13		V
CMRR Common mode rejection ratio	$R_S \leq 10\text{k}\Omega$, over temp.	70	90		70	90		dB
PSRR Power supply rejection	$R_S \leq 10\text{k}\Omega$, over temp.		30	150		30	150	$\mu\text{V}/\text{V}$
R_{IN} Input resistance		3	10		1	6		$\text{M}\Omega$
A_{VOL} Large signal voltage gain	$R_L \geq 2\text{k}\Omega$, $V_{OUT} = \pm 10\text{V}$ Over temp., $R_L \geq 2\text{k}\Omega$, $V_{OUT} = \pm 10\text{V}$	50 25	200		50 25	200		V/mV V/mV
V_{OUT} Output voltage	Over temp., $R_L \geq 2\text{k}\Omega$ Over temp., $R_L \geq 10\text{k}\Omega$	± 10 ± 12	± 13 ± 14		± 10 ± 12	± 13 ± 14		V V
I_{CC} Supply current	Per amplifier Over temp., per amplifier		2 2.2	3 3.6		2 2.2	3 3.6	mA mA
P_D Power dissipation	Per amplifier Over temp., per amplifier		60 66	90 108		60 66	90 108	mW mW
I_{SC} Output short circuit current		10	25	50	10	25	50	mA
R_{OUT} Output resistance			100			100		Ω

NOTE
Temperature Range
SE Types $-55^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$
NE Types $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$

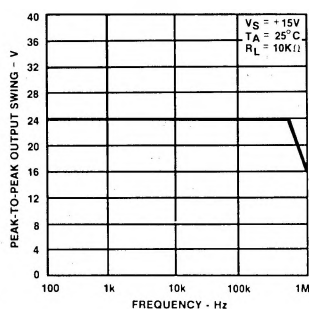
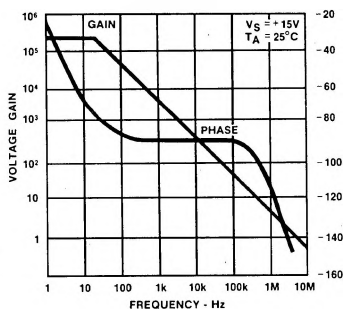
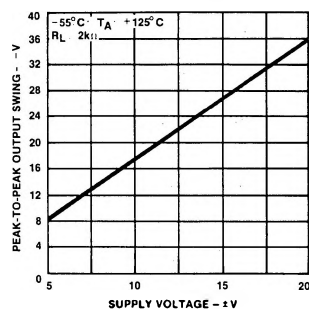
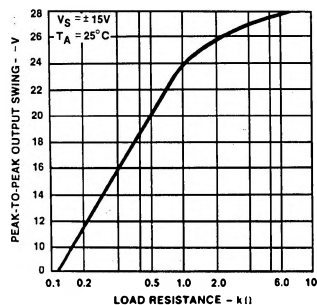
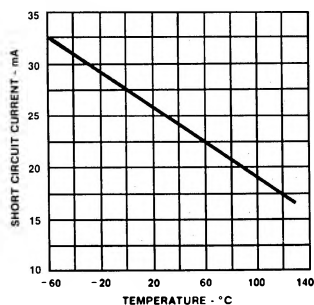
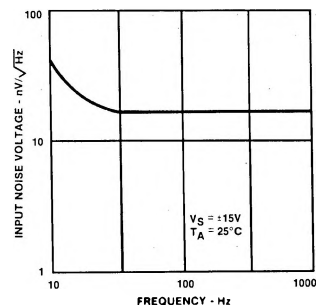
HIGH SLEW RATE OP AMP

SE/NE538

AC ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$ unless otherwise specified.

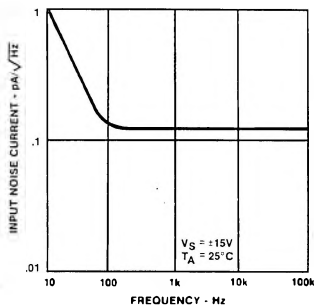
PARAMETER	TEST CONDITIONS	SE538/SE5538			SE538/NE5538			UNIT
		Min	Typ	Max	Min	Typ	Max	
Gain bandwidth product (Gain +5, -4 minimum)			6			6		MHz
Transient response			0.25			0.25		μs
Small signal rise time			6			6		%
Small signal overshoot			1.2			1.2		μs
Settling time	To 0.1%		1.2			1.2		μs
Slew rate	Minimum gain = 5 Noninverting $R_L \geq 2\text{k}\Omega$	40	60			60		$\text{V}/\mu\text{s}$
Input noise voltage	$f = 1\text{kHz}$, $T_A = 25^\circ\text{C}$		30			30		$\text{nV}/\sqrt{\text{Hz}}$

TYPICAL PERFORMANCE CHARACTERISTICS

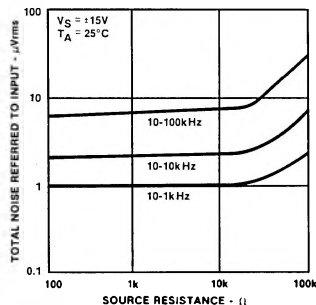
OUTPUT VOLTAGE SWING
AS A FUNCTION OF
FREQUENCYOPEN LOOP VOLTAGE GAIN
AS A FUNCTION OF
FREQUENCYOUTPUT VOLTAGE SWING
AS A FUNCTION OF
SUPPLY VOLTAGEOUTPUT VOLTAGE SWING
AS A FUNCTION OF
LOAD RESISTANCEOUTPUT SHORT-CIRCUIT CURRENT
AS A FUNCTION OF
AMBIENT TEMPERATUREINPUT NOISE VOLTAGE
AS A FUNCTION OF
FREQUENCY

TYPICAL PERFORMANCE CHARACTERISTICS (Cont'd)

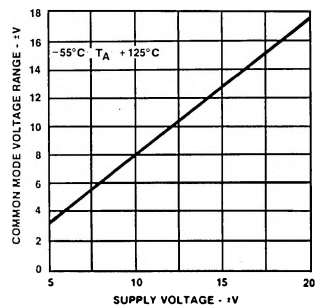
**INPUT NOISE CURRENT
AS A FUNCTION OF
FREQUENCY**



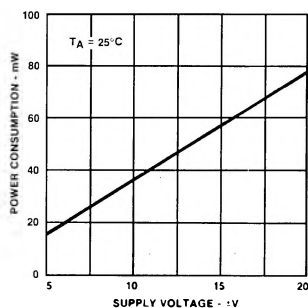
**BROADBAND NOISE FOR
VARIOUS BANDWIDTHS**



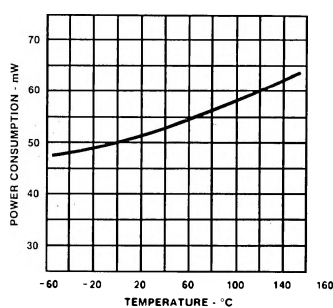
**INPUT COMMON MODE
VOLTAGE AS A
FUNCTION OF SUPPLY VOLTAGE**



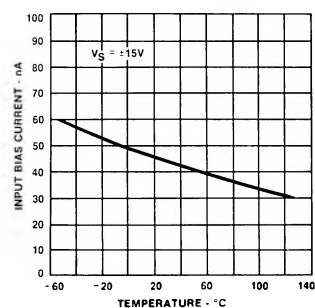
**POWER CONSUMPTION
AS A FUNCTION OF
SUPPLY VOLTAGE**



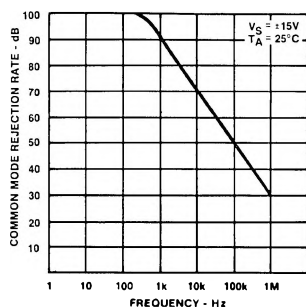
**POWER CONSUMPTION
AS A FUNCTION OF
AMBIENT TEMPERATURE**



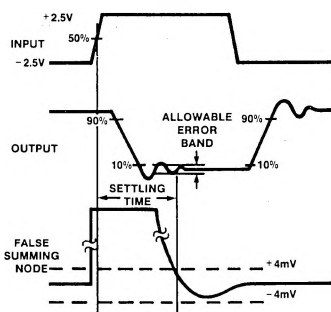
**INPUT BIAS CURRENT
AS A FUNCTION OF
AMBIENT TEMPERATURE**



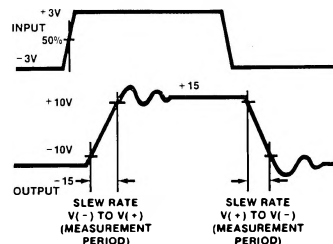
**COMMON MODE REJECTION
RATIO AS A FUNCTION OF
FREQUENCY**



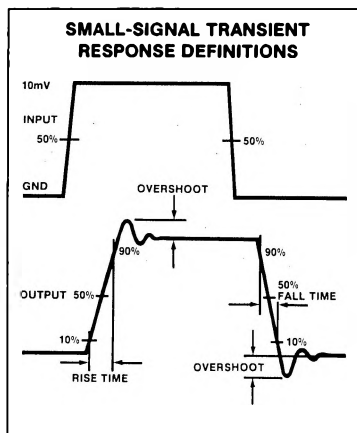
**SETTLING TIME MEASUREMENT
WAVEFORMS**



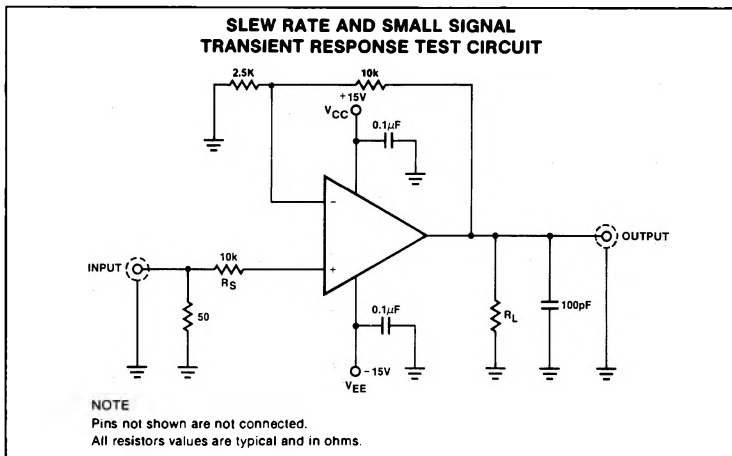
**SLEW RATE MEASUREMENT
VCC = ±20V**



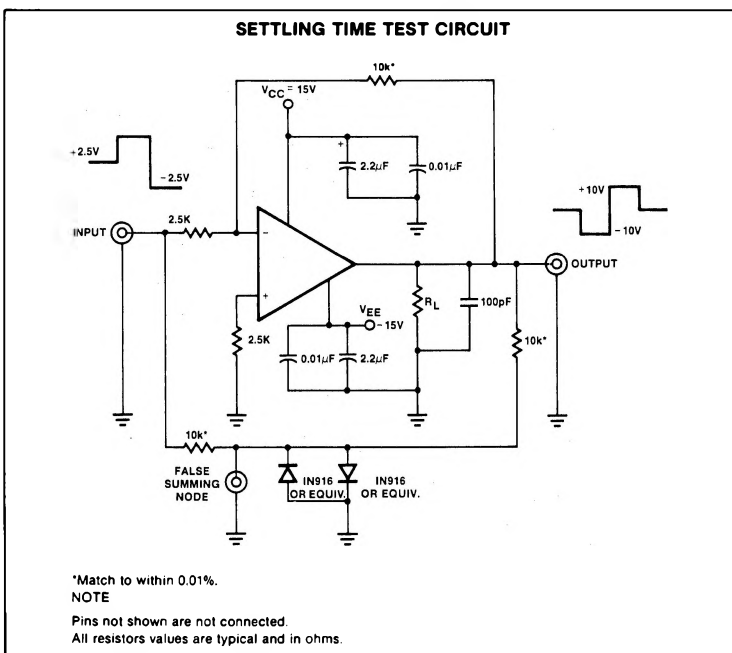
TYPICAL PERFORMANCE CHARACTERISTICS (Cont'd)



TEST LOAD CIRCUITS



TEST LOAD CIRCUITS (Cont'd)



HIGH SLEW RATE OP AMP

SE/NE538

INTRODUCTION

The Signetics NE538 is an undercompensated op amp. The NE538 has a typical slew rate of $50V/\mu s$ and a gain bandwidth product of 6MHz.

The internal frequency compensation is designed for a minimum inverting gain of 4 and a minimum non-inverting gain of 5. Below these gains the NE538 will be unstable and will need external compensation (see Figure 1 and 2).

The higher slew rate of the NE538 has made this device quite appealing for high speed designs and the fact that it has a standard pinout will allow it to be used to upgrade existing systems that now use the $\mu A741$ or $\mu 748$.

Equations:

$$f_{LAG} = \frac{1 (6MHz)}{10} = \frac{1}{2\pi R_L C_L}$$

$$f_{LEAD} = 6MHz = \frac{1}{2\pi R_F C_F}$$

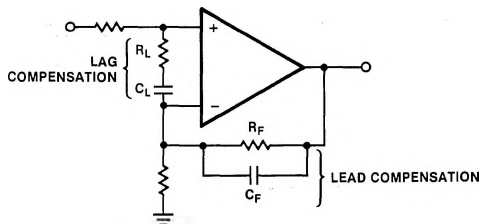


Figure 1. Non-Inverting Configuration

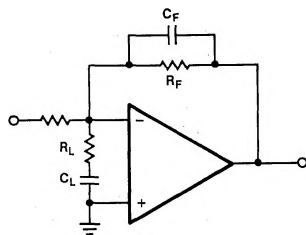


Figure 2. Inverting Configuration

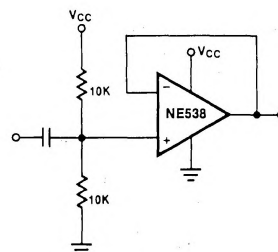


Figure 3. Voltage Follower with Single Power Source

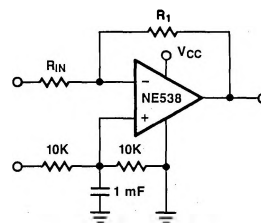


Figure 4. Inverting Amp With Single Power Supply

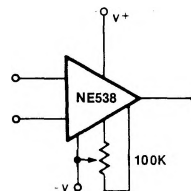
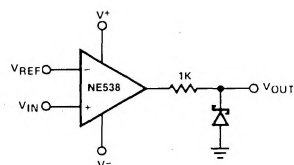


Figure 5. Offset Adjust Circuit



All resistor values are in ohms.

Figure 6. Voltage Comparator